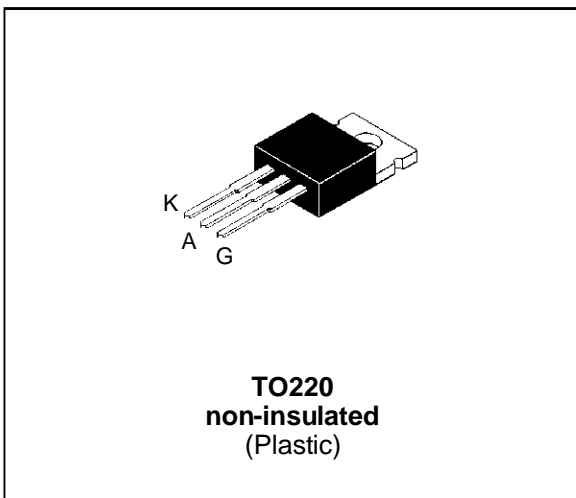


### FEATURES

- $I_{T(RMS)} = 40A$
- $V_{DRM} = 200V$  to  $800V$
- High surge current capability

### DESCRIPTION

The S40xxxH series of SCRs uses a high performance MESA GLASS PNP technology. These parts are intended for general purpose applications.



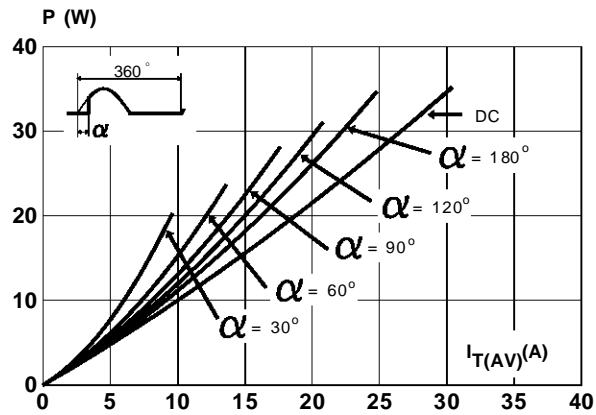
### ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
$I_{T(RMS)}$	RMS on-state current (180° conduction angle)	$T_c = 85^\circ C$	40	A
$I_{T(AV)}$	Average on-state current (180° conduction angle)	$T_c = 85^\circ C$	25	A
$I_{TSM}$	Non repetitive surge peak on-state current ( $T_j$ initial = $25^\circ C$ )	$t_p = 8.3$ ms	415	A
		$t_p = 10$ ms	380	
$I^2t$	$I^2t$ Value for fusing	$t_p = 10$ ms	722	$A^2s$
$di/dt$	Critical rate of rise of on-state current $I_G = 100$ mA $di_G/dt = 1$ A/ $\mu s$ .		100	A/ $\mu s$
$T_{stg}$ $T_j$	Storage and operating junction temperature range		- 40, + 150 - 40, + 125	$^\circ C$
TI	Maximum lead temperature for soldering during 10s at 4.5mm from case		260	$^\circ C$

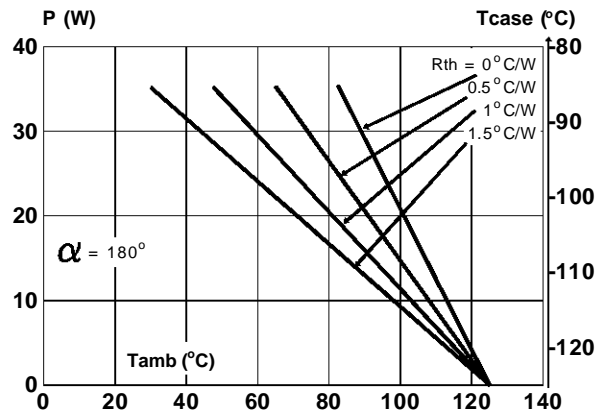
Symbol	Parameter	Voltage				Unit
		B	D	M	N	
$V_{DRM}$ $V_{RRM}$	Repetitive peak off-state voltage $T_j = 125^\circ C$	200	400	600	800	V



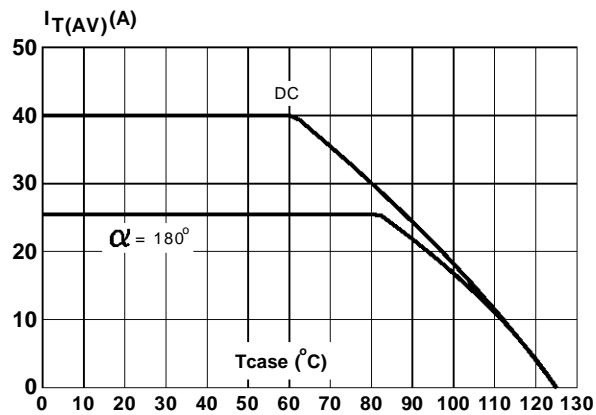
**Fig.1 :** Maximum average power dissipation versus average on-state current.



**Fig.2 :** Correlation between maximum average power dissipation and maximum allowable temperature (Tamb and Tcase) for different thermal resistances heatsink + contact.



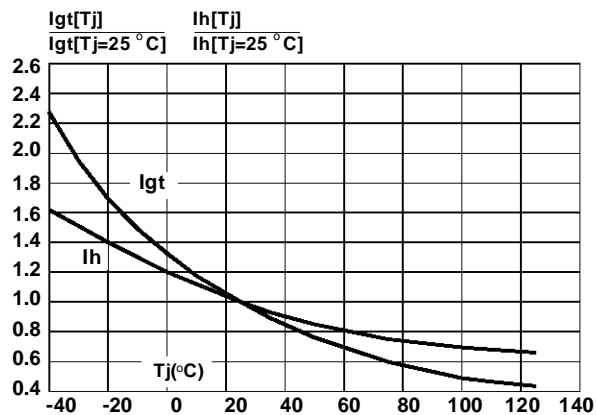
**Fig.3 :** Average on-state current versus case temperature.



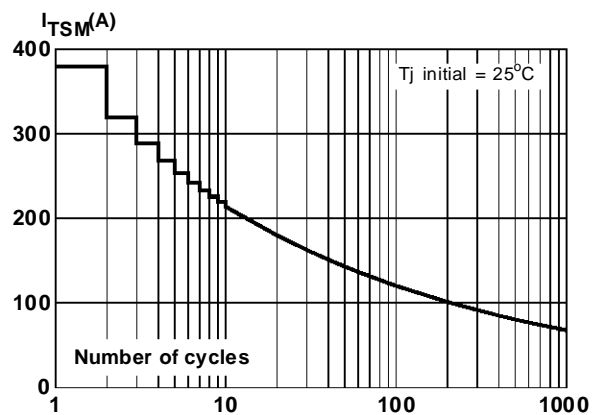
**Fig.4 :** Relative variation of thermal impedance versus pulse duration.



**Fig.5 :** Relative variation of gate trigger current and holding current versus junction temperature.

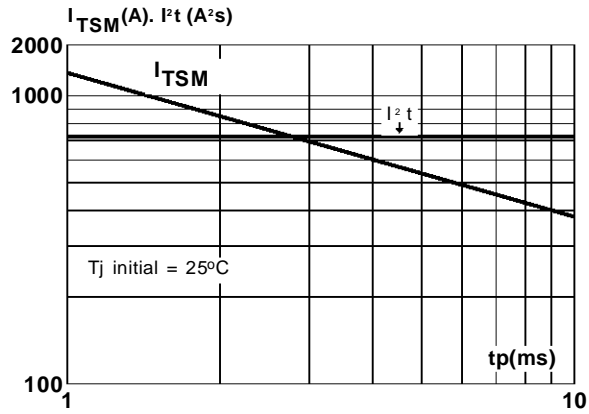


**Fig.6 :** Non repetitive surge peak on-state current versus number of cycles.

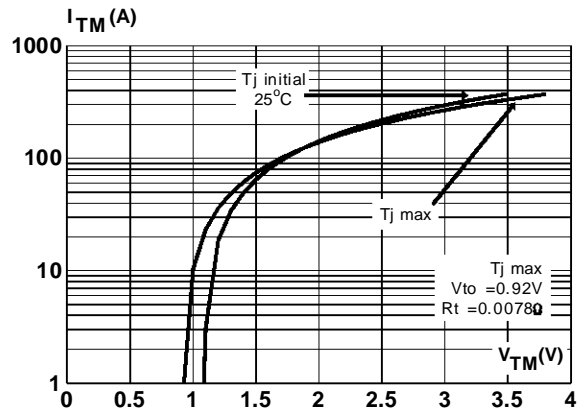


# S40xxxH

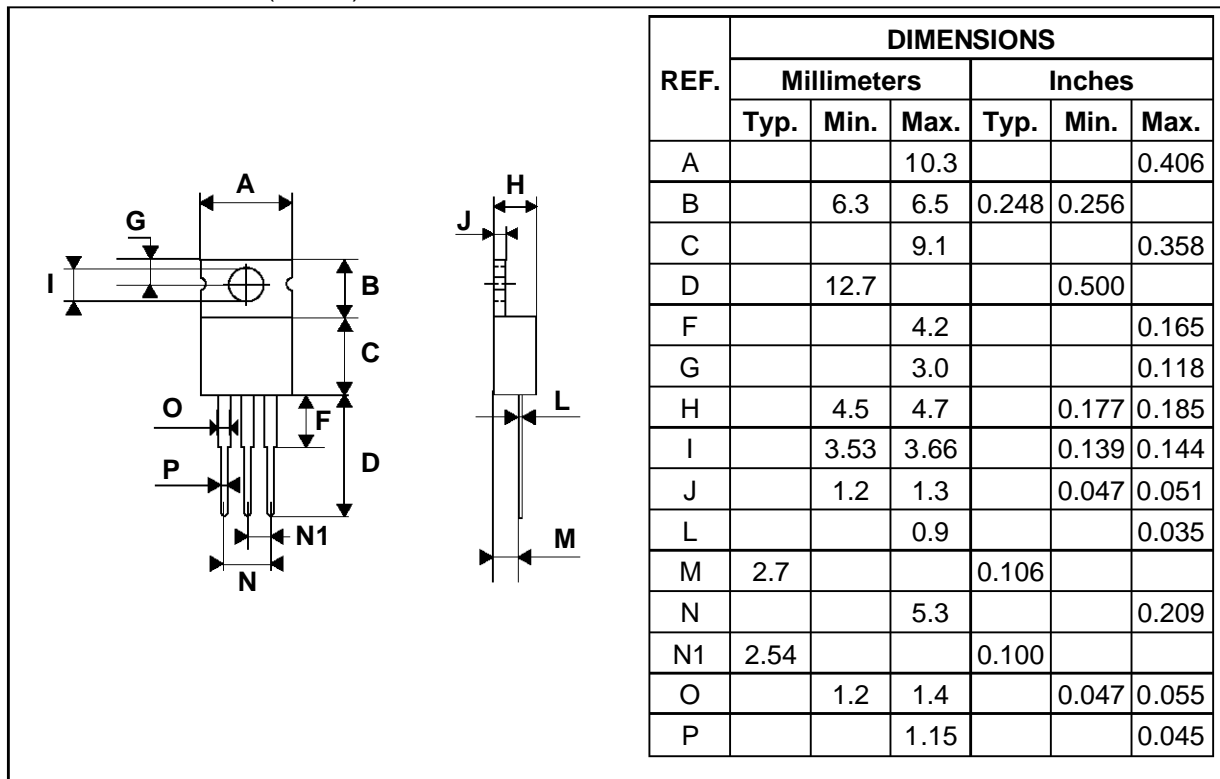
**Fig.7 :** Non repetitive surge peak on-state current for a sinusoidal pulse with width :  $t_p \leq 10\text{ms}$ , and corresponding value of  $I^2t$ .



**Fig.8 :** On-state characteristics (maximum values).



**PACKAGE MECHANICAL DATA**  
TO220 Non-insulated (Plastic)



Marking : type number  
Weight : 1.8 g

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